

SLPS202A - AUGUST 2009-REVISED SEPTEMBER 2010

N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD16406Q3

FEATURES

- **Ultra Low Qg and Qgd**
- **Low Thermal Resistance**
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 3.3mm x 3.3mm Plastic Package

TRUMENTS

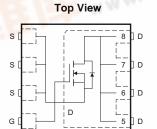
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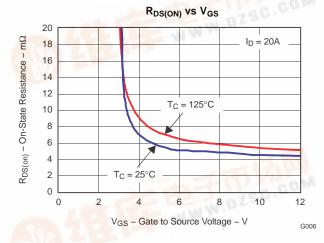
APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- **Optimized for Control or Synchronous FET Applications**

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage	25	V	
Q_g	Gate Charge Total (4.5V)	5.8		nC
Q_{gd}	Gate Charge Gate to Drain	1.5		nC
D	Design to Course On Design	V _{GS} = 4.5V	5.9	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V 4.2		mΩ
V _{th}	Threshold Voltage	1.8		V

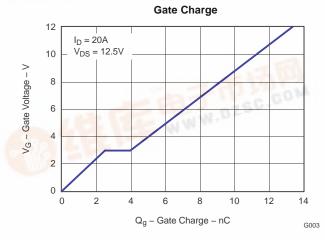
ORDERING INFORMATION

Device Package		Media	Qty	Ship
CSD16406Q3	SON 3.3 × 3.3 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 25	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	25	٧
V _{GS}	Gate to Source Voltage	+16 / -12	٧
W	Continuous Drain Current, T _C = 25°C	60	Α
ID	Continuous Drain Current ⁽¹⁾	19	Α
I_{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	114	Α
P_D	Power Dissipation ⁽¹⁾	2.7	W
T_J , T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	ů
E _{AS}	Avalanche Energy, single pulse I_D = 45A, L = 0.1mH, R_G = 25 Ω	101	mJ

- (1) $R_{\theta JA} = 46^{\circ} \text{C/W on 1in}^2 \text{ Cu (2 oz.) on 0.060" thick FR4 PCB.}$
- (2) Pulse width ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static C	haracteristics	•			*	
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 20V			1	μА
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +16/-12V$			100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.4	1.8	2.2	V
D	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 20A$		5.9	7.4	$m\Omega$
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 20A$		4.2	5.3	mΩ
g _{fs}	Transconductance	$V_{DS} = 15V, I_D = 20A$		53		S
Dynamic	C Characteristics					
C _{ISS}	Input Capacitance			840	1100	pF
Coss	Output Capacitance	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1MHz$		680	950	pF
C_{RSS}	Reverse Transfer Capacitance			57	80	pF
R _g	Series Gate Resistance			1.2	2.4	Ω
Q_g	Gate Charge Total (4.5V)			5.8	8.1	nC
Q_{gd}	Gate Charge Gate to Drain	V _{DS} = 12.5V, I _D = 20A		1.5		nC
Q_{gs}	Gate Charge Gate to Source	V _{DS} = 12.3V, I _D = 20A		2.5		nC
Qg(th)	Gate Charge at Vth			1.5		nC
Q _{OSS}	Output Charge	$V_{DS} = 13.6V, V_{GS} = 0V$		13.9		nC
t _{d(on)}	Turn On Delay Time			7.3		ns
t _r	Rise Time	$V_{DS} = 12.5V, V_{GS} = 4.5V I_{D} = 20A$		12.9		ns
t _{d(off)}	Turn Off Delay Time	$R_G = 2\Omega$		8.5		ns
t _f	Fall Time			4.8		ns
Diode C	haracteristics					
V_{SD}	Diode Forward Voltage	$I_{S} = 20A, V_{GS} = 0V$		0.85	1.0	V
Q _{rr}	Reverse Recovery Charge	V_{DD} = 13.6V, I_F = 20A, di/dt = 300A/ μ s		18		nC
t _{rr}	Reverse Recovery Time	$V_{DD} = 13.6V$, $I_F = 20A$, $di/dt = 300A/\mu s$		22		ns

THERMAL CHARACTERISTICS

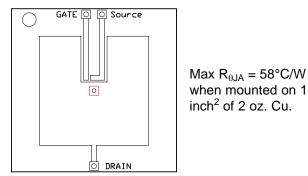
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

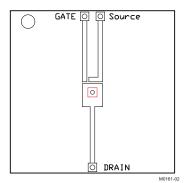
	PARAMETER	MIN	TYP	MAX	UNIT
R $_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			2.7	°C/W
R $_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾ (2)			58	°C/W

⁽¹⁾ $R_{\theta JC}$ is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 x 1.5 in 0.06 inch thick FR4 board. $R_{\theta JC}$ is specified by design while $R_{\theta JA}$ is determined by the user's board design.

(2) Device mounted on FR4 Material with 1 inch² of 2 oz. Cu.

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Max $R_{\theta JA} = 162^{\circ}C/W$ when mounted on minimum pad area of 2 oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

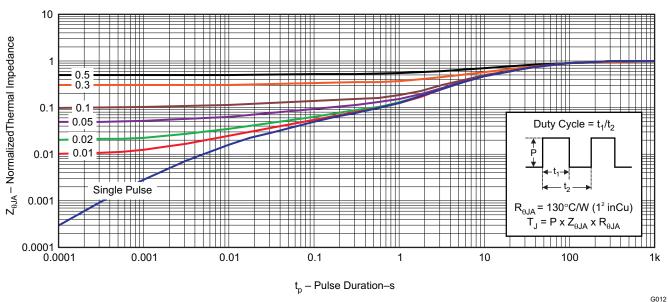


Figure 1. Transient Thermal Impedance



TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

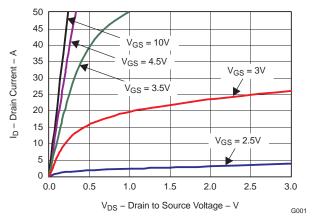


Figure 2. Saturation Characteristics

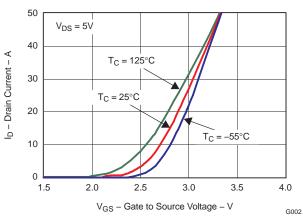


Figure 3. Transfer Characteristics

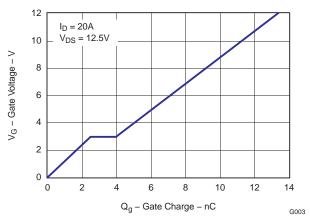


Figure 4. Gate Charge

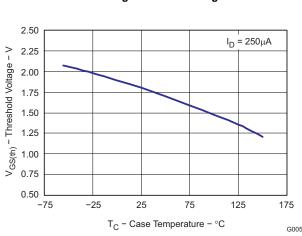


Figure 6. Threshold Voltage vs. Temperature

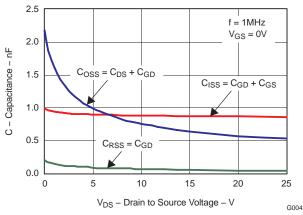


Figure 5. Capacitance

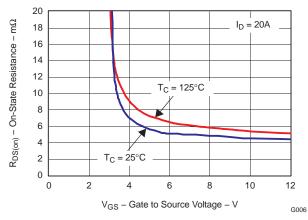


Figure 7. On Resistance vs. Gate Voltage

ISTRUMENTS

TYPICAL MOSFET CHARACTERISTICS (continued)

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

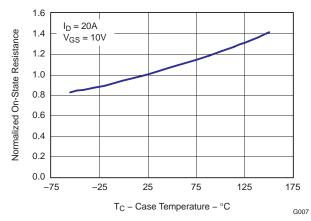


Figure 8. Normalized On Resistance vs. Temperature

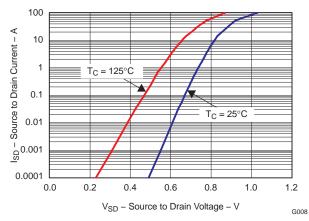


Figure 9. Typical Diode Forward Voltage

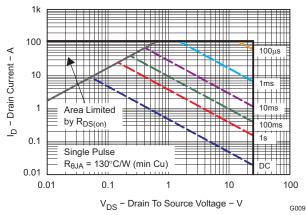


Figure 10. Maximum Safe Operating Area

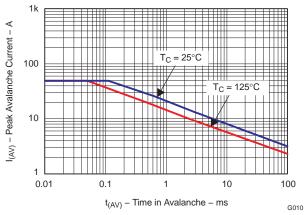


Figure 11. Single Pulse Unclamped Inductive Switching

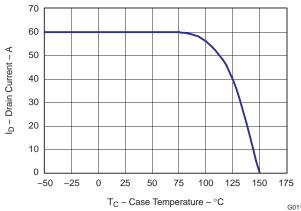
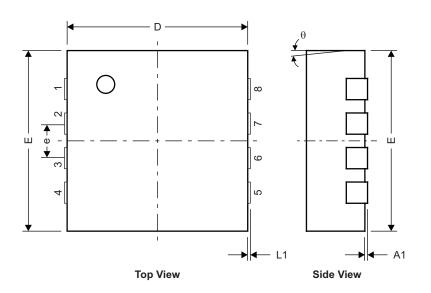


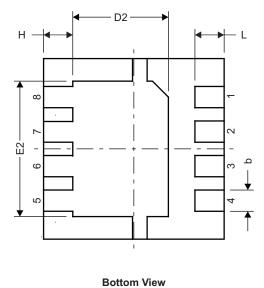
Figure 12. Maximum Drain Current vs. Temperature

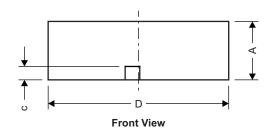


MECHANICAL DATA

Q3 Package Dimensions





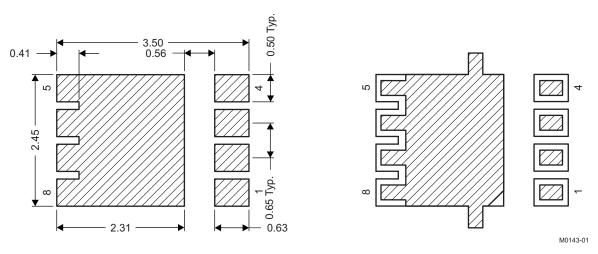


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DIM	MILLIMETERS			INCHES			
	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.950	1.000	1.100	0.037	0.039	0.043	
A1	0.000	0.000	0.050	0.000	0.000	0.002	
b	0.280	0.340	0.400	0.011	0.013	0.016	
С	0.150	0.200	0.250	0.006	0.008	0.010	
D	3.200	3.300	3.400	0.126	0.130	0.134	
D1	-	-	Í	_	-	_	
D2	1.650	1.750	1.800	0.065	0.069	0.071	
E	3.200	3.300	3.400	0.126	0.130	0.134	
E1	-	-	-	_	_	_	
E2	2.350	2.450	2.550	0.093	0.096	0.100	
е		0.650 TYP			0.026		
Н	0.35	0.450	0.550	0.014	0.018	0.022	
L	0.35	0.450	0.550	0.014	0.018	0.022	
L1	-	-	-	_	_	_	
θ	_	_	_	_	-	_	

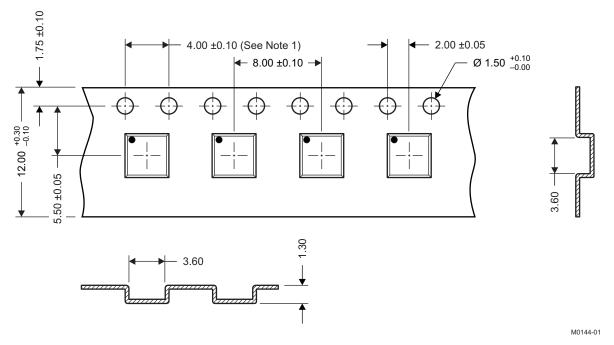
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Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q3 Tape and Reel Information



Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible





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REVISION HISTORY

Cł	nanges from Original (August 2009) to Revision A	Page	ļ
•	Deleted the Package Marking Information section	7	,



PACKA

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Pea
CSD16406Q3	ACTIVE	SON	DQG	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-2600

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retard in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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